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Black Lithium Niobate Wafer

(LiNbO3 Optical Grade)

When different types of ions are mixed into the LiNbO3 crystal, it exhibits various special properties, making it suitable for applications such as optical waveguide amplifiers, frequency-doubling converters, and optical storage media.

For example, in high-power laser applications, magnesium oxide-doped crystals (MgO:LiNbO3) are used. They have a higher Laser Damage Threshold. At the same time, the doping has no effect on the optical properties of the crystal.

We can provide doped LN wafers: Er:LN, MgO:LN and Fe:LN with customized doping dose.

Product Parameters

Material	3" 4" 6" LN wafer (Optical grade)
Orientation	X & Z
Surface finish	single or double sides polish (DLP/SLP/SSP/DSP all available)
Thickness	0.18/0.25/0.35/0.50/1.00 mm
TTV	<1~5µm
BOW	± (25μm ~40um)
Warp	<= 35μm
LTV (5mmx5mm)	<1.5 um
PLTV(<0.5um)	≥98% (5mm*5mm) with 2mm edge excluded
Curie Temp	1142°C±3°C
Edge	Compl't with SEMI M1.2@with GC800#. regular at C typed
Orientation flats	available, per request
Doped with	Er:LN, MgO:LN, Fe:LN, Er:MgO:LN
Polished side Ra	Roughness Ra<=5A
Back Side Criteria	Roughness Ra:0.5-1.0µm GC#1000
Edge Rounding	Compliant with SEMI M1.2 Standard/refer to IEC62276
Cracks, saw marks, stains	None
Single Domain	Completed Polarization/Reduced
Doped with Polished side Ra Back Side Criteria Edge Rounding Cracks, saw marks, stains	Er:LN, MgO:LN, Fe:LN, Er:MgO:LN Roughness Ra<=5A Roughness Ra:0.5-1.0µm GC#1000 Compliant with SEMI M1.2 Standard/refer to IEC62276 None

Please contact us for customer specific requirements and questions